

Multi Layer Ceramic Capacitors

Introduction

SAMWHA's series of multilayer ceramic (MLC) chip capacitors is designed to meet a wide variety of need. Multilayer ceramic chip capacitors are available in both class I and class II formulations. Temperature compensation formulations are class I and temperature stable and general application formulations are classified at class II. The class I multilayer ceramic capacitors are COG with negligible dependence of electrical properties on temperature, voltage, frequency. The most of commonly used class II dielectric are X7R, X5R and Y5V. The X7R provides intermediate capacitance values which vary $\pm 15\%$ over the temperature range of -55°C to 125°C . The X5R provides intermediate capacitance values which vary $\pm 15\%$ over the temperature range of -55°C to 85°C . The Y5V provides the highest capacitance value which vary from 22% to -82% over the temperature range of -30°C to 85°C . All class II capacitors vary in capacitance value under the influence of temperature, operating voltage and frequency. We offer a complete line of products for both class I and II.

Features

- Samwha's high density ceramic bodies offer superior performance and reliability
- Samwha offer various temperature characteristics, rated voltage and packing method
- Material with high dielectric constant and superior manufacturing technology allows very high values in a small size
- Solder coated terminals offer superior solderability

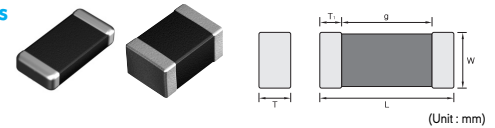
Applications

Wide applications throughout commercial and industrial market.

- Communication products like Cellular Phone, Pager, Codeless phone
- Multimedia products like DVD, CD-ROM, FDD, HDD, Game machine, Computer, Note book, Digital camera, LCD
- Audio visual products like TV, Camcorder, Minidisk, MP3 Player
- Communication products like Electronic tuner, Duplexer, VCXO, TCXO, Modem
- OA equipment products like Printer, Copy Machine, Fax Machine

SMD Type

Shape & Dimensions



Code(inch)	Dimensions					T1(min)
	Length		Width		T1(min)	
	L	Tol(\pm)	W	Tol(\pm)		
0603(0201)	0.60	0.03	0.30	0.03	0.05	
1005(0402)	1.00	0.05	0.50	0.05	0.05	
1608(0603)	1.60	0.15	0.80	0.10	0.10	
2012(0805)	2.00	0.20	1.25	0.15	0.10	
3216(1206)	3.20	0.30	1.60	0.20	0.15	
3225(1210)	3.20	0.40	2.50	0.25	0.15	
4520(1808)	4.50	0.40	2.00	0.25	0.20	
4532(1812)	4.50	0.40	3.20	0.30	0.20	
5750(2300)	5.70	0.50	5.00	0.40	0.30	

*1608 Size $\geq 10^4 f$ \Rightarrow W : 0.8 ± 0.15 , T : 0.8 ± 0.15

How to Order(Product Identification)

CS 1608 X7R 104 K 160 N R B

1 2 3 4 5 6 7 8 9

1 Type

CS : SMD

SA : ARRAY

2 Size Code

This is expressed in tens of a millimeter.

The first two digits are the length, the last two digits are width.

Size(mm)	0603	1005	1608	2012	3216	3225	4520	4532	5750
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3 Temperature Coefficient Code

Temperature Characteristic	Temperature Range	Capacitance Change or Temperature Coefficient	Operating Temperature Range
COG	-55 to 125°C	$0 \pm 30 \text{ppm}/^{\circ}\text{C}$	-55 to 125°C
X7R	-55 to 125°C	$\pm 15\%$	-55 to 125°C
X5R	-55 to 85°C	$\pm 15\%$	-55 to 85°C
Y5V	-30 to 85°C	$+22, -82\%$	-30 to 85°C

4 Capacitance Code(Pico Farads)

The nominal capacitance value in pF is expressed by three digit numbers.
The first two digits represents significant figures and the last digit denotes the number of zero
Ex.) 104 = 10000pF R denotes decimal 8R2 = 8.2pF

5 Capacitance Tolerance Code

Code	Tolerance	Code	Tolerance
B	±0.1pF	M	±20%
C	±0.25pF	P	+100, -0%
D	±0.5pF	Z	+80, -20%
F	±1.0%	H	+0.25/-0pF
G	±2.0%	I	+0/-0.25pF
J	±5%	U	+5/-0%
K	±10%	V	+0/-5%

6 Voltage Code

Code	6R3	100	160	250	500	101	201	251	631	302
Vol.	DC 6.3V	DC 10V	DC 16V	DC 25V	DC 50V	DC 100V	DC 200V	DC 250V	DC 630V	DC 3000V

7 Termination Code

Ex.) N : Ni-Sn (Nickel-Tin Plate)

8 Packing Code

Ex.) R : Reel Type B : Bulk Type

9 Thickness Option

(Unit : mm)

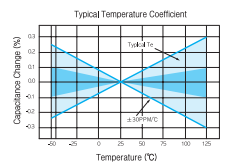
Code	Thickness(mm)		Code	Thickness(mm)	
	L	To(±)		W	To(±)
Blank	0.30	0.03	E	1.30	0.20
Blank	0.50	0.05	H	1.35	0.20
A	0.60	0.10	I	1.60	0.20
B	0.80	0.10	J	1.80	0.20
B	0.85	0.15	K	2.00	0.25
E	1.00	0.15	L	2.50	0.25
E	1.10	0.15	M	2.80	0.30
E	1.15	0.15	N	3.20	0.30
E	1.25	0.15	O	5.00	0.40

Typical Performance Characteristics**COG****Application**

Suited for precision circuits, requiring stable dielectric characteristics, negligible dependence of capacitance and dissipation factor on time, voltage and frequency.

Dielectric Characteristics

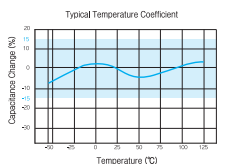
Temperature Characteristic	0 ± 30ppm/°C
Operating Temperature	-55~125°C
Capacitance Tolerance	> 10pF : ±5%, ±10%, (±1%, ±2%, ±20%) ≤ 10pF : ±0.1pF, ±0.25pF, ±0.5pF
Dissipation Factor & Q	≥ 30pF : DF ≤ 0.1%, Q ≥ 1000 < 30pF : Q ≥ 400+20 × C
Insulation Resistance	More than 10,000MΩ or 500QF (Whichever is smaller)
Dielectric Strength	> 3 × RVDC
Test Voltage	0.5 to 5Vrms(≤ 1000pF), 1 ± 0.2Vrms(> 1000pF)
Test Frequency	1 ± 0.1MHz(≤ 1000pF), 1 ± 0.1kHz(> 1000pF)

**X7R****Application**

Stable class II dielectric properties, suited for by-pass and coupling purposes, filtering, frequency discrimination, DC blockage, and as voltage transient suppression elements.

Dielectric Characteristics

Temperature Characteristic	± 15%
Operating Temperature	-55~125°C
Capacitance Tolerance	± 10%, ± 20%, (± 5%, +80~-20%)
Dissipation Factor & Q	50V Min. : 2.5% Max. 25V Min. : 3.0% Max. 16V Min. : 3.5% Max. 10V Min. : 5.0% Max. 6.3V Min. : 5.0% Max.(< 3.3μF), 10% Max.(≥ 3.3μF) Thin layer large capacitors type 10% Max.
Insulation Resistance	More than 10,000MΩ or 500QF(Whichever is smaller) Thin layer large capacitors type 50QF Min.
Dielectric Strength	> 2.5 × RVDC
Test Voltage	1 ± 0.2Vrms(≤ 10μF, 10V Min.) 0.5 ± 0.1Vrms(≤ 10μF, 6.3V Max.) 0.5 ± 0.1Vrms(> 10μF)
Test Frequency	1 ± 0.1kHz(≤ 10μF, 10V Min.) 1 ± 0.1kHz(≤ 10μF, 6.3V Max.) 120 ± 24Hz(> 10μF)



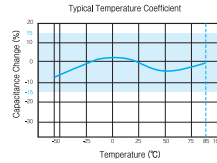
X5R

Application

Stable class II dielectric properties, suited for by-pass and coupling purposes, filtering, frequency discrimination, DC blockage, and as voltage transient suppression elements.

Dielectric Characteristics

Temperature Characteristic	±15%
Operating Temperature	-55~85°C
Capacitance Tolerance	±10%, ±20%, (±5%, +80~-20%)
Dissipation Factor & Q	50V Min. : 2.5% Max. 25V Min. : 3.0% Max. 16V Min. : 3.5% Max. 10V Min. : 5.0% Max. 6.3V Min. : 5.0% Max. (<3.3µF), 10% Max. (≥3.3µF) Thin layer lange capacitors type 10% Max.
Insulation Resistance	More than 10,000MΩ or 500QF (Whichever is smaller) Thin layer lange capacitors type 50QF Min.
Dielectric Strength	>2.5×RVDC
Test Voltage	1±0.2Vrms(≤10µF, 10V Min.) 0.5±0.1Vrms(≤10µF, 6.3V Max.) 0.5±0.1Vrms(>10µF)
Test Frequency	1±0.1kHz(≤10µF, 10V Min.) 1±0.1kHz(≤10µF, 6.3V Max.), 120±24Hz(>10µF)



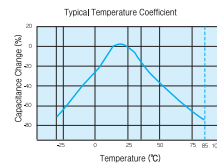
Y5V

Application

The Hi-K(Y5V) dielectrics deliver high capacitance density and are ideally suited for applications where space is at a premium, or as replacement for tantalum capacitors. Typically applications include use as by-pass or decoupling elements. Best performance is obtained at or near room temperature, with low DC bias.

Dielectric Characteristics

Temperature Characteristic	+22%~-82%
Operating Temperature	-30~85°C
Capacitance Tolerance	-20~+80%(±20%)
Dissipation Factor & Q	50V Min. : 5% Max. 25V Min. : 7% Max. 16V Min. : 9% Max. 10V Min. : 12.5% Max. 6.3V Min. : 15% Max. Thin layer lange capacitors type 20% Max.
Insulation Resistance	More than 10,000MΩ or 500QF (Whichever is smaller) Thin layer lange capacitors type 50QF Min.
Dielectric Strength	>2.5×RVDC
Test Voltage	1±0.2Vrms(≤10µF, 10V Min.) 0.5±0.1Vrms(≤10µF, 6.3V Max.) 0.5±0.1Vrms(>10µF)
Test Frequency	1±0.1kHz(≤10µF, 10V Min.) 1±0.1kHz(≤10µF, 6.3V Max.), 120±24Hz(>10µF)



Appendix I

COG-Temperature Compensating Type(0603~3216)

Type Size(inch) Vol(V) Cap.	COG								
	0603(0201)		1005(0402)		1608(0603)		2012(0805)		3216(1206)
	25	25	50	25	50	25	50	25	50
0.5µF (085)									
1µF (010)									
2µF (020)									
3µF (030)									
4µF (040)									
5µF (050)									
6µF (060)									
7µF (070)									
8µF (080)									
9µF (090)									
10µF (100)									
12µF (120)									
15µF (150)									
18µF (180)									
22µF (220)									
27µF (270)									
33µF (330)									
39µF (390)									
47µF (470)									
56µF (560)									
68µF (680)									
82µF (820)									
100µF (100)									
120µF (120)									
150µF (150)									
180µF (180)									
220µF (220)									
270µF (270)									
330µF (330)									
390µF (390)									
470µF (470)									
560µF (560)									
680µF (680)									
820µF (820)									
1000µF (1000)									
1200µF (1200)									
1500µF (1500)									
1800µF (1800)									
2200µF (2200)									
2700µF (2700)									
3300µF (3300)									
3900µF (3900)									
4700µF (4700)									
5600µF (5600)									
6800µF (6800)									
8200µF (8200)									
10000µF (10000)									
12000µF (12000)									
15000µF (15000)									
18000µF (18000)									
22000µF (22000)									
27000µF (27000)									
33000µF (33000)									
47000µF (47000)									
56000µF (56000)									
68000µF (68000)									
82000µF (82000)									
0.1µF (014)									

Temperature Compensating Type : Dissipation Factor Page 22 (No.5)

Appendix II

X7R-High Dielectric Constant Type(0603~3225) & Thin Layer Large-Capacitance Type

Type	X7R																							
	0603(0201)				1005(0402)				1608(0603)				2012(0805)				3216(1206)				3225(1210)			
	6.3	10	16	25	6.3	10	16	25	6.3	10	16	25	6.3	10	16	25	6.3	10	16	25	6.3	10	16	25
100µF(101)																								
470µF(471)																								
1000µF(102)																								
2200µF(222)																								
4700µF(472)																								
10000µF(103)																								
15000µF(153)																								
22000µF(223)																								
33000µF(333)																								
47000µF(473)																								
68000µF(683)																								
0.1µF(104)																								
0.15µF(154)																								
0.22µF(224)																								
0.33µF(334)																								
0.47µF(474)																								
0.68µF(684)																								
1.0µF(105)																								
1.5µF(155)																								
2.2µF(225)																								
4.7µF(475)																								
6.8µF(685)																								
10µF(106)																								
22µF(226)																								
47µF(476)																								
100µF(107)																								

- General Type : Dissipation Factor Page 22 (No.5)
- * General Type : Dissipation Factor Page 22 (No.5)
- Thin Layer Large-Capacitance Type : Dissipation Factor Page 22 (No.5)

X5R-High Dielectric Constant Type(0603~3225) & Thin Layer Large-Capacitance Type

Type	X5R																							
	0603(0201)				1005(0402)				1608(0603)				2012(0805)				3216(1206)				3225(1210)			
	6.3	10	16	25	6.3	10	16	25	6.3	10	16	25	6.3	10	16	25	6.3	10	16	25	6.3	10	16	25
100µF(101)																								
470µF(471)																								
1000µF(102)																								
2200µF(222)																								
4700µF(472)																								
10000µF(103)																								
15000µF(153)																								
22000µF(223)																								
33000µF(333)																								
47000µF(473)																								
68000µF(683)																								
0.1µF(104)																								
0.15µF(154)																								
0.22µF(224)																								
0.33µF(334)																								
0.47µF(474)																								
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4.7µF(475)																								
6.8µF(685)																								
10µF(106)																								
22µF(226)																								
47µF(476)																								
100µF(107)																								

- General Type : Dissipation Factor Page 22 (No.5)
- * General Type : Dissipation Factor Page 22 (No.5)
- Thin Layer Large-Capacitance Type : Dissipation Factor Page 22 (No.5)

SMD Type-High Voltage

Y5V-High Dielectric Constant Type(0603~3225) & Thin Layer Large-Capacitance Type

Type	Y5V																								
	1005(0402)				1608(0603)				2012(0805)				3216(1206)				3225(1210)								
Size(inch)																									
Vol(V)																									
Cap.	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
1000µF (102)																									
2200µF (222)																									
4700µF (472)																									
10000µF (103)																									
15000µF (153)																									
22000µF (223)																									
33000µF (333)																									
47000µF (473)																									
68000µF (683)																									
0.1µF (104)																									
0.15µF (154)																									
0.22µF (224)																									
0.33µF (334)																									
0.47µF (474)																									
0.68µF (684)																									
1.0µF (105)																									
1.5µF (155)																									
2.2µF (225)																									
3.3µF (335)																									
4.7µF (475)																									
6.8µF (685)																									
10µF (106)																									
22µF (226)																									
47µF (476)																									
100µF (107)																									

■ General Type : Dissipation Factor Page 22 (No.5)
■ * General Type : Dissipation Factor Page 22 (No.5)
■ Thin Layer Large-Capacitance Type : Dissipation Factor Page 22 (No.5)

Product Offering

SAMWHA high voltage MLCC products with COG(NPO) and X7R temperature characteristic are designed for commercial and industrial applications. The products are power supply and voltage multiplier circuits applications in various sizes with working voltages up to DC 3.0 KV. These high voltage capacitors feature a special internal electrode design which reduces voltage concentrations by distributing voltage gradients throughout the entire capacitor. This unique design also affords that capacitance value is increased in a given case size and voltage rating.

Features

- High reliability
- High voltage ratings
- Wide voltage level : from 100V to 3000V
- Surface mount suited for Wave and Reflow Soldering
- Tape & reel surface mount assembly
- Suitable for Back-Lighting Inverter, DC-DC Converters, Ballast, Modems & Power Supply, LAN/WLAN interface... etc.

How to Order(Product Identification)

CS 4520 COG 150 J 302 N R E

1 2 3 4 5 6 7 8 9

1 Type

CS : SMD

2 Size Code

Size(mm)	1608	2012	3216	3225	4520	4532
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3 Dielectric (Temp. Coefficient)

COG, X7R

4 Capacitance

1st two digits are value, 3rd digit denotes number of zeros;
 331 = 330pF, 104 = 10000pF, 8R2C = 8.2pF

5 Tolerance

Code	Tolerance	Code	Tolerance
B	±0.1pF	C	±0.25pF
D	±0.50pF	F	±1%
G	±2%	J	±5%
K	±10%	M	±20%
Z	+80~-20%		

6 Rated Voltage Code

1st two digits are value, 3rd digit denotes number of zeros; 302 = 3000V, 251 = 250V

7 Plating

Ni / Sn Plated

8 Packing

B : Bulk Pack R : Reel Pack

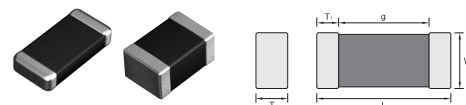
9 Thickness Option

(Unit : mm)

Code	Thickness(mm)		Code	Dimensions	
	L	To(±)		W	To(±)
Blank	0.30	0.05	E	1.30	0.20
Blank	0.50	0.05	H	1.35	0.20
A	0.60	0.10	I	1.60	0.20
B	0.80	0.10	J	1.80	0.20
B	0.85	0.15	K	2.00	0.25
E	1.00	0.15	L	2.50	0.25
E	1.10	0.15	M	2.80	0.30
E	1.15	0.15	N	3.20	0.30
E	1.25	0.15	O	5.00	0.40

SMD Type-High Voltage

Shape & Dimensions



(Unit : mm)

Code	Dimensions				
	Length		Width		T1(min)
L	To(±)	W	To(±)		
1608(0603)	1.60	0.15	0.80	0.10	0.10
2012(0805)	2.00	0.20	1.25	0.15	0.10
3216(1206)	3.20	0.30	1.60	0.20	0.15
3225(1210)	3.20	0.40	2.50	0.25	0.15
4520(1808)	4.50	0.40	2.00	0.25	0.20
4532(1812)	4.50	0.40	3.20	0.30	0.20
5750(2300)	5.70	0.50	5.00	0.40	0.30

*1608 Size $\geq 10\mu\text{F} \Rightarrow W : 0.8 \pm 0.15, T : 0.8 \pm 0.15$

Typical Performance Characteristics

Dielectric Characteristics	COG(NPO)	X7R
	Dielectric Classification	Ultra Stable
Rated temperature range	-55°C to +125°C	-55°C to +125°C
TCC(Temperature Characteristics Coefficient)	0 ± 30ppm	± 15%
Dissipation Factor(tan δ)	C ≥ 30pF : Q ≥ 1,000 (DF: ≤ 0.1%) C < 30pF : Q ≥ 400+20C(DF: ≤ 1/(400+20C))	2.5% Max.
IR(Insulation Resistance)	500V Below : Rated voltage 60sec 500V Above : 500V 60sec More than 10,000 MΩ	500V Below:Rated voltage 60sec 500V Above:500V 60sec -DC100V-1KV :C ≥ 0.01μF:More than 100MΩ :C < 0.01μF:More than 10,000MΩ -DC2-3KV:More than 6,000 MΩ
Capacitance Tolerance	<10pF : ± 0.25pF, ± 0.5pF ≥ 10pF : ± 5%, ± 0%	± 10%, ± 20%
Dielectric strength	630V:150% Rated Voltage 1kV-3.15kV:120% Rated Voltage	100V:150% Rated Voltage 630V:150% Rated Voltage 1kV-3.15kV: 120% Rated Voltage
Aging characteristics	0%	2.5% per decade hr, typical

Appendix High Voltage Type(100V~3000V)

COG-Temperature Compensation Type

Type	COG																			
	1608(0603)		2012(0805)		3216(1206)				3225(1210)				4520(1808)				4532(1812)			
	100	250	100	250	100	250	630	1000	2000	100	250	630	1000	2000	100	250	630	1000	2000	3000
4.7µF(4R7)																				
5µF(050)																				
7µF(070)																				
8µF(080)																				
9µF(090)																				
10µF(100)																				
12µF(120)																				
15µF(150)																				
18µF(180)																				
22µF(220)																				
47µF(470)																				
56µF(560)																				
68µF(680)																				
82µF(820)																				
100µF(101)																				
220µF(221)																				
330µF(331)																				
470µF(471)																				
560µF(561)																				
680µF(681)																				
1000µF(102)																				
1500µF(152)																				
2200µF(222)																				
2700µF(272)																				
3300µF(332)																				
4700µF(472)																				
5600µF(562)																				
6800µF(682)																				
10000µF(103)																				
15000µF(153)																				
22000µF(223)																				
33000µF(333)																				

High voltage type

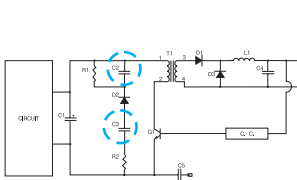
X7R-High Dielectric Type

Type	X7R																			
	1608(0603)		2012(0805)		3216(1206)				3225(1210)				4520(1808)				4532(1812)			
	100	250	100	250	100	250	630	1000	2000	100	250	630	1000	2000	100	250	630	1000	2000	3000
220µF(221)																				
330µF(331)																				
470µF(471)																				
680µF(681)																				
1000µF(102)																				
1500µF(152)																				
2200µF(222)																				
3300µF(332)																				
4700µF(472)																				
5600µF(562)																				
6800µF(682)																				
10000µF(103)																				
15000µF(153)																				
18000µF(183)																				
22000µF(223)																				
33000µF(333)																				
47000µF(473)																				
68000µF(683)																				
0.1µF(104)																				
0.15µF(154)																				
0.22µF(224)																				
0.33µF(334)																				
0.47µF(474)																				
0.68µF(684)																				
1.0µF(105)																				
2.2µF(225)																				

High voltage type

Application(Typical circuit)

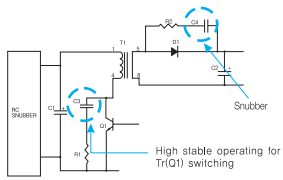
DC-DC Converter



High stable operating for Tr(Q1) switching

C2 : X7R ; 250V 10nF-47nF
C3 : COG ; 630V 47pF-100pF

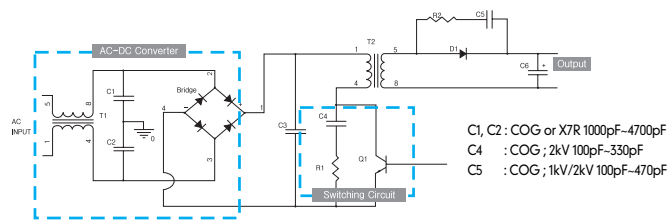
Switching Power Supply



High stable operating for Tr(Q1) switching

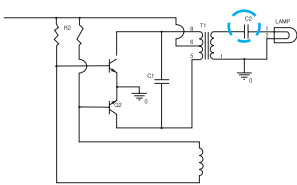
C3 : COG, X7R; 2kV 100pF-1000pF
C4 : COG, X7R; 2kV 100pF-1000pF

Primary circuit and Snubber switching power supply



C1, C2 : COG or X7R 1000pF-4700pF
C4 : COG ; 2kV 100pF-330pF
C5 : COG ; 1kV/2kV 100pF-470pF

LCD back light Inverter



C2 : COG ; 3kV 10-100pF

Caution(Rating)

1. Operating Voltage

When DC-rated capacitors are to be used in AC or ripple current circuits, be sure to maintain the Vp-p Value of the applied voltage or the Vo-p which contains DC bias within the rated voltage range. When the voltage is applied to the circuit, starting or stopping may generate irregular voltage for a transit period because of resonance or switching. Be sure to use a capacitor with a rated voltage range that includes these irregular voltages.

Voltage	DV Voltage	DC+AC Voltage	AC Voltage	Pulse Voltage(1)	Pulse Voltage(2)
Positional Measurement					

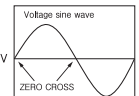
2. Test condition for AC withstanding Voltage

(1) Test Equipment

Tests for AC withstanding voltage should be made with equipment capable of creating a wave similar to a 50/60 Hz sine wave. If the distorted sine wave or overload exceeding the specified voltage value is applied, a defect may be caused.

(2) Voltage applied method

The capacitor's leads or terminals should be firmly connected to the output of the withstanding voltage test equipment, and then the voltage should be raised from near zero to the test voltage. If the test voltage is applied directly to the capacitor without raising it from near zero, it should be applied with the *zero cross. At the end of the test time, the test voltage should be reduced to near zero, and then the capacitor's leads or terminals should be taken off the output of the withstanding voltage test equipment. If the test voltage is applied directly to the capacitor without raising it from near zero, surge voltage may occur and cause a defect. *ZERO CROSS is the point where voltage sine wave



(3) Dielectric strength testing method

In case of dielectric strength test, the capacitor's is applied between the terminations for 1 to 5 sec., provided the charge/discharge current is less than 50mA.

3. Soldering

If a chip component is heated or cooled abruptly during soldering, it may crack due to the thermal shock. To prevent this, follow our recommendations below for adequate soldering conditions. Carefully perform preheating so that temperature difference (ΔT) between the solder and component surface is in the following range. The smaller the temperatures difference (ΔT) between the solder and component surface is, the smaller the influence on the chip is.

Chip Size	3.2×1.6mm and under	3.2×2.5mm and over
Soldering Method		
Reflow Method or Soldering Iron Method	$\Delta T \leq 190^{\circ}\text{C}$	$\Delta T \leq 130^{\circ}\text{C}$

SAMWHA CAPACITOR CO., LTD offers a line of MLCC(Multilayer Ceramic Capacitor). These parts are rated at 3kV dc and safety approved and certified to UL (Underwriters Laboratories Inc. ®)

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NWGQ8.E304146

Information Technology Equipment Including Electrical Business Equipment Certified for Canada - Component

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See General Information for Information Technology Equipment Including Electrical Business Equipment Certified for Canada - Component

SAMWHA CAPACITOR CO LTD E304146

124 BLK-RI
NANSA-MYEUN
YONGIN-SHI, KYONGGI-DO 449-880 REPUBLIC OF KOREA

Component Recognition, Model(s) CS45XXYYTTTA302NRE.



Marking: Company name, model designation and Recognized Component Mark for Canada, **UL**

Last Updated on 2006-04-28

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Reliability and Test Conditions(General Type)

No.	Item	Characteristic		Test Methods and Conditions																																													
		Temperature Compensating Type	High Dielectric Constant Type																																														
1	Operating Temperature Range	COG : -55 to +125°C	X7R : -55 to +125°C; X5R : -55 to +85°C Y5V : -30 to +85°C																																														
2	Insulation Resistance	More than 10,000MΩ or 500Q/F(Whichever is smaller)		- Applied the rated voltage for 2 minutes of charging. - The charge/discharge current is less than 50mA.																																													
3	Dielectric Strength	No defects or abnormalities		- COG : The rated voltage × 300% - X7R, X5R, Y5V : - × 250% - Applied between the terminations for 1 to 5 seconds. - The charge/discharge current is less than 50mA.																																													
4	Capacitance	Within the specified tolerance																																															
5	Dissipation Factor	30µF Min. : Q ≥ 1,000 (DF ≤ 0.1%) 30µF Max. : Q ≥ 400+20C (DF ≤ 1/(400+20C))	<table border="1"> <thead> <tr> <th>Char.</th> <th>50V Min.</th> <th>25V</th> <th>16V</th> <th>10V</th> <th>6.3V</th> </tr> </thead> <tbody> <tr> <td>X7R</td> <td>≤ 2.5%</td> <td>≤ 3%</td> <td>≤ 3.5%</td> <td>≤ 5%</td> <td>≤ 5%</td> </tr> <tr> <td>X5R</td> <td>+ ≤ 5%</td> <td>+ ≤ 7%</td> <td>+ ≤ 7%</td> <td>+ ≤ 10%</td> <td>+ ≤ 10%</td> </tr> <tr> <td>Y5V</td> <td>≤ 5%</td> <td>≤ 7%</td> <td>≤ 9%</td> <td>≤ 12.5%</td> <td>≤ 15%</td> </tr> <tr> <td></td> <td>+ ≤ 9%</td> <td>+ ≤ 9%</td> <td>+ ≤ 12.5%</td> <td>+ ≤ 15%</td> <td></td> </tr> </tbody> </table>	Char.	50V Min.	25V	16V	10V	6.3V	X7R	≤ 2.5%	≤ 3%	≤ 3.5%	≤ 5%	≤ 5%	X5R	+ ≤ 5%	+ ≤ 7%	+ ≤ 7%	+ ≤ 10%	+ ≤ 10%	Y5V	≤ 5%	≤ 7%	≤ 9%	≤ 12.5%	≤ 15%		+ ≤ 9%	+ ≤ 9%	+ ≤ 12.5%	+ ≤ 15%		<p>The capacitance/Q/D.F. should be measured at 25°C at the frequency and voltage shown in the table.</p> <table border="1"> <thead> <tr> <th>Cop.</th> <th>Testing Frequency</th> <th>Testing Voltage</th> </tr> </thead> <tbody> <tr> <td>COG (C ≤ 1000pF)</td> <td>1 ± 0.1MHz</td> <td>0.5 to 5Vrms</td> </tr> <tr> <td>COG (C) 1000pF</td> <td>1 ± 0.1kHz</td> <td>1 ± 0.2Vrms</td> </tr> <tr> <td>X7R, X5R, Y5V (C ≤ 10µF, 6.3V Min.)</td> <td>1 ± 0.1kHz</td> <td>1 ± 0.2Vrms</td> </tr> <tr> <td>X7R, X5R, Y5V (C) 10µF</td> <td>120 ± 24Hz</td> <td>0.5 ± 0.1Vrms</td> </tr> </tbody> </table> <p>* You can check the specification at the appendix for each product with mark</p>	Cop.	Testing Frequency	Testing Voltage	COG (C ≤ 1000pF)	1 ± 0.1MHz	0.5 to 5Vrms	COG (C) 1000pF	1 ± 0.1kHz	1 ± 0.2Vrms	X7R, X5R, Y5V (C ≤ 10µF, 6.3V Min.)	1 ± 0.1kHz	1 ± 0.2Vrms	X7R, X5R, Y5V (C) 10µF	120 ± 24Hz	0.5 ± 0.1Vrms
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6	Solderability of Termination	Termination should be covered with more than 75% of new solder		- Pb-Free Type Solder : 96.5Sn-3Ag-0.5Cu Solder Temperature : 260 ± 5°C Immersion Time : 3 ± 0.1sec - Pre-Heating at 80-120°C for 10-30sec																																													
7	Resistance to Soldering Heat	Appearance	No marked defect		- Preheat the capacitor at 120 to 150°C for 1 minute. (Preheating for 3Z25, 4520, 4532 Step1: 100°C to 120°C, 1min Step2: 170°C to 200°C, 1min) Immerse the capacitor in a eutectic solder solution - Soldering Temp. : 260 ± 5°C - Immersion Time : 10 ± 0.5sec - Initial measurement Perform a heat treatment at 150±0, -10°C for one hour and then let sit for 48 ± 4 hours at room temperature. Perform the initial measurement. - Measurement after test Take it out and set it for 24 ± 2 hours (temperature compensating type) or 48 ± 4 hours (high dielectric constant type) then measure																																												
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9	Humidity Load	No marking defects				- Temperature : 40±2°C - Humidity : 90~95% - Hour : 500±12hrs - Test Voltage : The rated voltage - Take it out and set it for 24±2 hours (temperature compensating) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA																		
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10	High Temperature Load	No marking defects				- Testing time : 1000±12hrs - Applied voltage : Rated voltage < DC250V : ×200% - Temperature : C0G, X7R → 125±3°C X5R, Y5V → 85±3°C - Measurement after test Take it out and set it for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.																		
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11	Bending Strength	<p>No cracking or marking defects shall occur</p>				- Substrate Material : Glass EPOXY Board - Board Thickness : 1.6mm - 0.8mm (0403/1005size) ※ Test Condition - Bending Limit : 1mm - Pressurizing Speed : 1mm/sec																		
	Capacitance Change	Within ±5% or ±0.5µF (whichever is larger)	X7R, X5R : Within ±12.5% Y5V : Within ±30%																					
12	Vibration Resistance	No defects or abnormalities				+ Shown in Fig. After soldering and then let sit for 24±4hr (temperature compensating type), 48±4hr (high dielectric constant type) at room temperature. The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz, shall be traversed (from 10Hz to 55Hz then 10Hz again) in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total is 6hrs).																		
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10	High Temperature Load	No marking defects				- Testing time : 1000±12hrs - Applied voltage : Rated voltage < DC250V : ×200% - Temperature : C0G, X7R → 125±3°C X5R, Y5V → 85±3°C - Measurement after test Take it out and set it for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.																		
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	Dissipation Factor (or Q)	30µF Min. : Q≥350 (DF≤0.3%) 10µF ≤ Cp ≤ 30µF : Q≥275 +5/2C (DF≤1/(275+5/2C)) 10µF Max. : Q≥200+10C (DF≤1/(200+10C))	<table border="1"> <thead> <tr> <th>Char. 50V Min.</th> <th>25V</th> <th>16V</th> <th>10V</th> <th>6.3V</th> </tr> </thead> <tbody> <tr> <td>X7R</td> <td>≤5%/+5%</td> <td>≤5%/+5%</td> <td>≤7.5%/+7.5%</td> <td>≤7.5%/+7.5%</td> </tr> <tr> <td>X5R</td> <td>≤7.5%/+10%</td> <td>≤10%/+10%</td> <td>≤12.5%/+12.5%</td> <td>≤12.5%/+12.5%</td> </tr> <tr> <td>Y5V</td> <td>≤7.5%/+12.5%</td> <td>≤10%/+15%</td> <td>≤15%/+20%</td> <td>≤20%</td> </tr> </tbody> </table>				Char. 50V Min.	25V	16V	10V	6.3V	X7R	≤5%/+5%	≤5%/+5%	≤7.5%/+7.5%	≤7.5%/+7.5%	X5R	≤7.5%/+10%	≤10%/+10%	≤12.5%/+12.5%	≤12.5%/+12.5%	Y5V	≤7.5%/+12.5%	≤10%/+15%
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11	Bending Strength	<p>No cracking or marking defects shall occur</p>				- Substrate Material : Glass EPOXY Board - Board Thickness : 1.6mm - 0.8mm (0403/1005size) ※ Test Condition - Bending Limit : 1mm - Pressurizing Speed : 1mm/sec																		
	Capacitance Change	Within ±5% or ±0.5µF (whichever is larger)	X7R, X5R : Within ±12.5% Y5V : Within ±30%																					
12	Vibration Resistance	No defects or abnormalities				+ Shown in Fig. After soldering and then let sit for 24±4hr (temperature compensating type), 48±4hr (high dielectric constant type) at room temperature. The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz, shall be traversed (from 10Hz to 55Hz then 10Hz again) in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total is 6hrs).																		
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13	Humidity Steady State	No marking defects				- Temperature : 40±2°C - Humidity : 90~95% - Hour : 500±12hours - Measurement after test Take it out and set it for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.																		
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Radial & Axial

No.	Item	Characteristic			Test Methods and Conditions																									
		Temperature Compensating Type	High Dielectric Constant Type																											
14	Capacitance Temperature Change		<table border="1"> <thead> <tr> <th>Char.</th> <th>Temp. Range</th> <th>Reference Temp.</th> <th>Cap. Change</th> </tr> </thead> <tbody> <tr> <td>X7R</td> <td>-55 to +125°C</td> <td rowspan="3">25°C</td> <td>Within ±15%</td> </tr> <tr> <td>X5R</td> <td>-55 to +85°C</td> <td>Within ±15%</td> </tr> <tr> <td>Y5V</td> <td>-30 to +85°C</td> <td>Within 22% -82%</td> </tr> </tbody> </table>	Char.	Temp. Range	Reference Temp.	Cap. Change	X7R	-55 to +125°C	25°C	Within ±15%	X5R	-55 to +85°C	Within ±15%	Y5V	-30 to +85°C	Within 22% -82%	<p>(1) Temperature Compensating Type: The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, (COG: +25 to 125°C) the capacitance shall be within the specified tolerance for the temperature coefficient. The capacitance drift is calculated by dividing the difference between the maximum measured values in the step 1, 3 and 5 by the Cap. value in step 3</p> <table border="1"> <thead> <tr> <th>Step</th> <th>Temperature(°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>-55±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>125±3(for COG)</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> <p>(2) High Dielectric Constant Type : The ranges of capacitance change compared with the 25°C value over the temperature range shown in the table shall be in the specified range.</p>	Step	Temperature(°C)	1	25±2	2	-55±3	3	25±2	4	125±3(for COG)	5	25±2
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15	Preservation(keeping)	※ When solderability is considered, capacitors are recommended to be used in 12 months			(1) Temperature : 25°C ±10°C (2) Relative Humidity : Below 70% RH																									
16	The regulation of environmental pollution materials.	※ Never use materials mentioned below in MLCC products regulated this document. Pb, Cd, Hg, Cr+6, PBB(polybromide biphenyl), PBDE(polybrominated diphenyl ethers), asbestos.																												

- In case of high Voltage and thin layer type Capacitor, it can be different from normal specification.
So Please ask to our sales person.

Features

This widely used ceramic capacitors includes both monolithic and multilayer types to provide a wide capacitance range of 1pF through 1μF in respectively one standard size and shape(Radial & Axial).

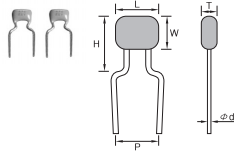
Applications

The class1 temperature compensating(COG) products can be used in circuits to stabilize frequency and temperature characteristics.
The X7R, Z5U, Y5V dielectrics are optimum for by pass capacitors.

Shape and Dimensions

Bulk Type

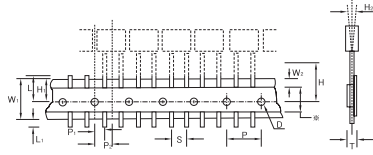
Radial Type



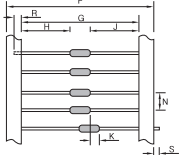
CODE	L Max.	W Max.	T Max.	H Max.	P ±0.7	Ød	Color	Marking
051B	5.5	5.5	3.2	6.4	5	0.5	Orange or Gold	Ex) 104
077B	7.7	7.6		9.2				

Flat Type

Radial Type



Axial Type



Code	Dimensions	Tolerance	Code	Dimensions	Tolerance
D(Ø)	4	±0.3	P1	3.85	±0.7
H	16	±0.5	P2	6.35	±1.3
H1	9	+0.76, -0.5	T	0.9	Max.
H2	0	±2	W1	18	±0.5
L	11	Max.	W2	0	+0.6 Max.
L1	1.5	Max.	S	5	±0.7
P	12.7	±0.3	*	No adhesive may be exposed	

Code	Dimensions	Tolerance
F	64.8	-0, +2
G	50.8-53.3	
H	=J	±1.2
J	=H	±1.2
K	0.8	Max.
N	5	±0.4
R	3.2	Min.

How to Order(Product Identification)

CA 2633 Y5V 104 Z 500 F



- 1 Type**
CR : Radial Lead Type
CA : Axial Lead Type
- 2 Dimension Code**
The number shows the maximum length of "L" by 1/10 in millimeter, and the alphabet means lead difference.(Refer to above diagram)

3 Temperature Coefficient Code

Temperature Characteristic	Temperature Range	Capacitance Change or Temperature Coefficient
C0G	-55 to 125°C	0±30ppm/°C
X7R	-55 to 125°C	±15%
Z5U	10°C to 85°C	+22, -56%
Y5V	-30 to 85°C	+22, -82%

4 Capacitance Code(Pico Farads)

First two digits are significant; third digit denotes number of zeros.
Ex.) 101 = 100pF, 1R5 = 1.5pF, 103 = 10,000pF

5 Capacitance Tolerance Code

Code	Tolerance	Remark
J	± 5.0 %	C0G
K	±10 %	X7R, C0G
M	± 20 %	Z5U, X7R
Z	+80, -20%	Z5U, Y5V

6 Rated Voltage Code

Code	250	500	101
Volt	DC 25V	DC 50V	DC 100V

7 Packing Code

Code	B	R	F
Packing	Bulk	Reel Pack	Flat Pack

Reliability and Test Conditions

No.	Item	Characteristic				Test Methods and Conditions		
		Temperature Compensating Type		High Dielectric Constant Type				
1.	Operating Temperature Range	C0G : -55 to +125°C		X7R : -55 to +125°C Z5U : +10 to +85°C				
2.	Insulation Resistance	More than 10,000MΩ or 500Ω,F(whichever is smaller)				Applied the rated voltage for 2 minute		
3.	Dielectric Strength	No detects or abnormalities				- C0G : The rated voltage ×300% - X7R, Z5U, Y5V : ×250%		
4.	Capacitance	Within the specified tolerance				Temperature Compensating Type		
5.	Dissipation Factor	30pF Min. : Q≥1,000(DF≤0.1%)		Char. 50V Min. 25V 16V 10V		Cap. Testing Frequency Testing Voltage		
		30pF Max. : Q≥400+20C (DF≤1/(400+20C))		X7R ≤2.5% ≤3% ≤3.5% ≤5.0% Z5V ≤4.0% - - - Y5V ≤5% ≤7% ≤9% ≤12.5% (≤220pF) (≥220pF)		C0G (C≤1000pF) 1±0.1kHz 0.5 to 5V rms C0G (C)1000pF 1±0.1kHz 1±0.2V rms X7R, Z5U, Y5V (C≤10pF 10V Min.) 1±0.1kHz 1±0.2V rms		
6.	Terminal Strength	No evidence of damage to body of device or looseness of terminals.				A static load of 10N(1kgf) : applied to one terminal in the axial direction and acting in a direction away from the body for 1 to 5 secs.		

No.	Item	Characteristic					Test Methods and Conditions																			
		Temperature Compensating Type	High Dielectric Constant Type																							
7.	Resistance to Soldering Heat	No marked defect					- Soldering Temp : 260±5°C - Immersion Time : 5±0.5sec - Take it out and set it for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) then measure.																			
	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	X7R : ≤± 7.5% Z5U, Y5V : ≤± 20%																							
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10.	High Temperature Load	No marked defect					- Testing Time : 1000±12hrs - Applied Voltage : Rated Voltage × 200% - Temperature : COG, X7R → 125±3°C Z5U, Y5V → 85±3°C																			
	Capacitance change	Within ±3% or ±0.3pF (whichever is larger)	X7R : Within ±12.5%, Z5U : Within ±30% Y5V : Within ±30% (Cap. < 1.0μF) Within ±30%, -40% (Cap. ≥ 1.0μF)																							

No.	Item	Characteristic					Test Methods and Conditions																						
		Temperature Compensating Type	High Dielectric Constant Type																										
10	High Temperature Load	Dissipation Factor(or Q)	30pF Min. : Q≥350 (DF≤0.3%) 10pF≤Cp≤30pF : Q≥275+5/2C (DF≤1/(275+5/2C)) 10pF Max. : Q≥200+10C (DF≤1/(200+10C))	<table border="1"> <tr> <th>Char.</th> <th>50V Min.</th> <th>25V</th> <th>16V</th> <th>10V</th> </tr> <tr> <td>X7R</td> <td>≤5%</td> <td>≤5%</td> <td>≤5%</td> <td>≤5%</td> </tr> <tr> <td>Z5U</td> <td>≤4.0%</td> <td>-</td> <td>-</td> <td>-</td> </tr> <tr> <td>Y5V</td> <td>≤7.5%</td> <td>≤10% (<1μF) ≤7% (≥1μF)</td> <td>≤12.5%</td> <td>≤15%</td> </tr> </table>	Char.	50V Min.	25V	16V	10V	X7R	≤5%	≤5%	≤5%	≤5%	Z5U	≤4.0%	-	-	-	Y5V	≤7.5%	≤10% (<1μF) ≤7% (≥1μF)	≤12.5%	≤15%					Take it out and set it for 24±2 hours (temperature compensating) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.
	Char.			50V Min.	25V	16V	10V																						
X7R	≤5%	≤5%	≤5%	≤5%																									
Z5U	≤4.0%	-	-	-																									
Y5V	≤7.5%	≤10% (<1μF) ≤7% (≥1μF)	≤12.5%	≤15%																									
	I.R.	More than 1000MΩ or 50ΩF (Whichever is smaller)																											
11	Capacitance Temperature Characteristics	Capacitance Change	<table border="1"> <tr> <th>Char.</th> <th>Temp. Range</th> <th>Reference Temp.</th> <th>Cap. Change</th> </tr> <tr> <td>X7R</td> <td>-55 to +125°C</td> <td>25°C</td> <td>Within ±15%</td> </tr> <tr> <td>Z5U</td> <td>-10 to +85°C</td> <td></td> <td>Within +22% -56%</td> </tr> <tr> <td>Y5V</td> <td>-30 to +85°C</td> <td></td> <td>Within +22% -82%</td> </tr> </table>	Char.	Temp. Range	Reference Temp.	Cap. Change	X7R	-55 to +125°C	25°C	Within ±15%	Z5U	-10 to +85°C		Within +22% -56%	Y5V	-30 to +85°C		Within +22% -82%	(1) Temperature Compensating Type : The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5. (SL -25 to 85°C) the capacitance shall be within the specified tolerance for the temperature coefficient. The capacitance drift is calculated dividing the difference between the maximum measured values in the step 1, 3 and 5 by Cap. value in step 3.									
	Char.			Temp. Range	Reference Temp.	Cap. Change																							
	X7R			-55 to +125°C	25°C	Within ±15%																							
Z5U	-10 to +85°C		Within +22% -56%																										
Y5V	-30 to +85°C		Within +22% -82%																										
Temperature Coefficient	<table border="1"> <tr> <th>Char.</th> <th>Temp. Range</th> <th>Temperature Coefficient</th> </tr> <tr> <td>COG</td> <td>-55 to +125°C</td> <td>±30ppm/°C</td> </tr> </table>	Char.	Temp. Range	Temperature Coefficient	COG	-55 to +125°C	±30ppm/°C	<table border="1"> <tr> <th>Step</th> <th>Temperature(°C)</th> </tr> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>-55±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>125±3 (or COG)</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </table> (2) High Dielectric Constant Type : The ranges of capacitance change compared with the 25°C value over the temperature range shown in the table shall be in the specified range.				Step	Temperature(°C)	1	25±2	2	-55±3	3	25±2	4	125±3 (or COG)	5	25±2						
Char.	Temp. Range	Temperature Coefficient																											
COG	-55 to +125°C	±30ppm/°C																											
Step	Temperature(°C)																												
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2	-55±3																												
3	25±2																												
4	125±3 (or COG)																												
5	25±2																												
12	The regulation of environmental pollution materials	※ Never use materials mentioned below in leaded MLCC products regulated this document. Pb, Cd, Hg, Cr ⁶⁺ , PBB (polybrominated biphenyl), PBDE (polybrominated diphenyl ethers), asbestos.																											
13	The regulation about destructive materials of the ozone layer	Never use the ODS (ozone depleting substance) materials below in leaded MLCC products regulated this document.																											

Packing Quantity

Unit : pcs

Radial Type			Axial Type		
Inner Box	Outer Box	Remark	Inner Box	Outer Box	Remark
2,500	15,000	Packing set on the basis of flat tapping	5,000	50,000	Packing set on the basis of flat tapping

Capacitance Range

Type Char.	Radial								Axial			
	COG		X7R		Z5U	Y5V		COG	X7R	Z5U	Y5V	
Cap(pF) \ Volt	50	100	50	100	50	16	50	50	50	50	50	
1												
2												
3												
4												
5												
6												
7												
8												
9												
10												
12												
15												
16												
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68												
75												
82												
91												
100												
120												
150												
180												
220												
270												
330												
390												
470												
560												
680												
820												
1.000												
1.200												
1.500												
1.800												
2.200												
2.700												
3.300												
3.900												
4.700												
5.600												
6.800												
8.200												
10.000												
15.000												
22.000												
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47.000												
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1.000.000												